

# MUN5230DW1, NSBC113EDXV6

## Dual NPN Bias Resistor Transistors

**R1 = 1 k $\Omega$ , R2 = 1 k $\Omega$**

### NPN Transistors with Monolithic Bias Resistor Network

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

#### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS

(T<sub>A</sub> = 25°C, common for Q<sub>1</sub> and Q<sub>2</sub>, unless otherwise noted)

| Rating                         | Symbol               | Max | Unit |
|--------------------------------|----------------------|-----|------|
| Collector-Base Voltage         | V <sub>CBO</sub>     | 50  | Vdc  |
| Collector-Emitter Voltage      | V <sub>CEO</sub>     | 50  | Vdc  |
| Collector Current – Continuous | I <sub>C</sub>       | 100 | mAdc |
| Input Forward Voltage          | V <sub>IN(fwd)</sub> | 10  | Vdc  |
| Input Reverse Voltage          | V <sub>IN(rev)</sub> | 10  | Vdc  |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### ORDERING INFORMATION

| Device                           | Package | Shipping <sup>†</sup> |
|----------------------------------|---------|-----------------------|
| MUN5230DW1T1G,<br>SMUN5230DW1T1G | SOT-363 | 3,000/Tape & Reel     |
| NSBC113EDXV6T1G                  | SOT-563 | 4,000/Tape & Reel     |

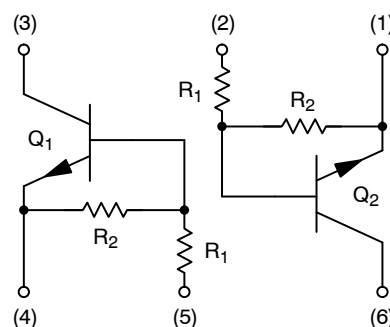
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



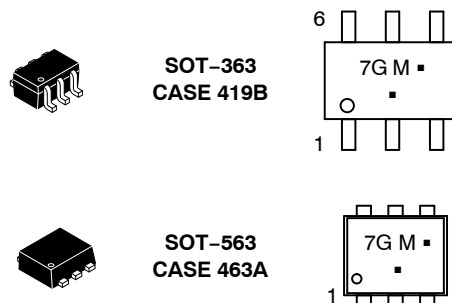
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#### PIN CONNECTIONS



#### MARKING DIAGRAMS



7G = Specific Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

# MUN5230DW1, NSBC113EDXV6

## THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|----------------|--------|-----|------|
|----------------|--------|-----|------|

### MUN5230DW1 (SOT-363) ONE JUNCTION HEATED

|                                                                                         |                                              |                 |                          |                            |
|-----------------------------------------------------------------------------------------|----------------------------------------------|-----------------|--------------------------|----------------------------|
| Total Device Dissipation<br>$T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | (Note 1)<br>(Note 2)<br>(Note 1)<br>(Note 2) | $P_D$           | 187<br>256<br>1.5<br>2.0 | mW<br>mW/ $^\circ\text{C}$ |
| Thermal Resistance,<br>Junction to Ambient                                              | (Note 1)<br>(Note 2)                         | $R_{\theta JA}$ | 670<br>490               | $^\circ\text{C/W}$         |

### MUN5230DW1 (SOT-363) BOTH JUNCTION HEATED (Note 3)

|                                                                                         |                                              |                 |                          |                            |
|-----------------------------------------------------------------------------------------|----------------------------------------------|-----------------|--------------------------|----------------------------|
| Total Device Dissipation<br>$T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | (Note 1)<br>(Note 2)<br>(Note 1)<br>(Note 2) | $P_D$           | 250<br>385<br>2.0<br>3.0 | mW<br>mW/ $^\circ\text{C}$ |
| Thermal Resistance,<br>Junction to Ambient                                              | (Note 1)<br>(Note 2)                         | $R_{\theta JA}$ | 493<br>325               | $^\circ\text{C/W}$         |
| Thermal Resistance,<br>Junction to Lead                                                 | (Note 1)<br>(Note 2)                         | $R_{\theta JL}$ | 188<br>208               | $^\circ\text{C/W}$         |
| Junction and Storage Temperature Range                                                  |                                              | $T_J, T_{stg}$  | -55 to +150              | $^\circ\text{C}$           |

### NSBC113EDXV6 (SOT-563) ONE JUNCTION HEATED

|                                                                                         |                      |                 |            |                            |
|-----------------------------------------------------------------------------------------|----------------------|-----------------|------------|----------------------------|
| Total Device Dissipation<br>$T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | (Note 1)<br>(Note 1) | $P_D$           | 357<br>2.9 | mW<br>mW/ $^\circ\text{C}$ |
| Thermal Resistance,<br>Junction to Ambient                                              | (Note 1)             | $R_{\theta JA}$ | 350        | $^\circ\text{C/W}$         |

### NSBC113EDXV6 (SOT-563) BOTH JUNCTION HEATED (Note 3)

|                                                                                         |                      |                 |             |                            |
|-----------------------------------------------------------------------------------------|----------------------|-----------------|-------------|----------------------------|
| Total Device Dissipation<br>$T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | (Note 1)<br>(Note 1) | $P_D$           | 500<br>4.0  | mW<br>mW/ $^\circ\text{C}$ |
| Thermal Resistance,<br>Junction to Ambient                                              | (Note 1)             | $R_{\theta JA}$ | 250         | $^\circ\text{C/W}$         |
| Junction and Storage Temperature Range                                                  |                      | $T_J, T_{stg}$  | -55 to +150 | $^\circ\text{C}$           |

- FR-4 @ Minimum Pad.
- FR-4 @  $1.0 \times 1.0$  Inch Pad.
- Both junction heated values assume total power is sum of two equally powered channels.

# MUN5230DW1, NSBC113EDXV6

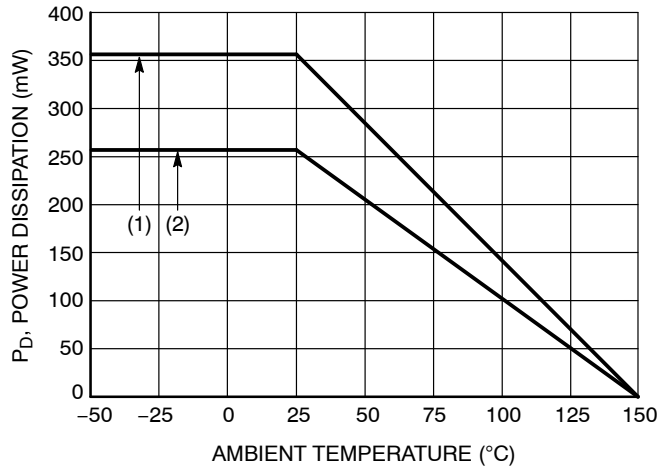
## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ , common for $Q_1$ and $Q_2$ , unless otherwise noted)

| Characteristic                                                                        | Symbol        | Min | Typ | Max | Unit |
|---------------------------------------------------------------------------------------|---------------|-----|-----|-----|------|
| <b>OFF CHARACTERISTICS</b>                                                            |               |     |     |     |      |
| Collector-Base Cutoff Current<br>( $V_{CB} = 50\text{ V}$ , $I_E = 0$ )               | $I_{CBO}$     | –   | –   | 100 | nAdc |
| Collector-Emitter Cutoff Current<br>( $V_{CE} = 50\text{ V}$ , $I_B = 0$ )            | $I_{CEO}$     | –   | –   | 500 | nAdc |
| Emitter-Base Cutoff Current<br>( $V_{EB} = 6.0\text{ V}$ , $I_C = 0$ )                | $I_{EBO}$     | –   | –   | 4.3 | mAdc |
| Collector-Base Breakdown Voltage<br>( $I_C = 10\text{ }\mu\text{A}$ , $I_E = 0$ )     | $V_{(BR)CBO}$ | 50  | –   | –   | Vdc  |
| Collector-Emitter Breakdown Voltage (Note 4)<br>( $I_C = 2.0\text{ mA}$ , $I_B = 0$ ) | $V_{(BR)CEO}$ | 50  | –   | –   | Vdc  |

## ON CHARACTERISTICS

|                                                                                                          |               |     |     |      |                  |
|----------------------------------------------------------------------------------------------------------|---------------|-----|-----|------|------------------|
| DC Current Gain (Note 4)<br>( $I_C = 5.0\text{ mA}$ , $V_{CE} = 10\text{ V}$ )                           | $h_{FE}$      | 3.0 | 5.0 | –    |                  |
| Collector-Emitter Saturation Voltage (Note 4)<br>( $I_C = 10\text{ mA}$ , $I_B = 5.0\text{ mA}$ )        | $V_{CE(sat)}$ | –   | –   | 0.25 | V                |
| Input Voltage (Off)<br>( $V_{CE} = 5.0\text{ V}$ , $I_C = 100\text{ }\mu\text{A}$ )                      | $V_{i(off)}$  | –   | 1.2 | –    | Vdc              |
| Input Voltage (On)<br>( $V_{CE} = 0.2\text{ V}$ , $I_C = 20\text{ mA}$ )                                 | $V_{i(on)}$   | –   | 1.7 | –    | Vdc              |
| Output Voltage (On)<br>( $V_{CC} = 5.0\text{ V}$ , $V_B = 2.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ )   | $V_{OL}$      | –   | –   | 0.2  | Vdc              |
| Output Voltage (Off)<br>( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.05\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) | $V_{OH}$      | 4.9 | –   | –    | Vdc              |
| Input Resistor                                                                                           | $R_1$         | 0.7 | 1.0 | 1.3  | $\text{k}\Omega$ |
| Resistor Ratio                                                                                           | $R_1/R_2$     | 0.8 | 1.0 | 1.2  |                  |

4. Pulsed Condition: Pulse Width = 300 ms, Duty Cycle  $\leq 2\%$ .



(1) SOT-363; 1.0 x 1.0 Inch Pad  
(2) SOT-563; Minimum Pad

Figure 1. Derating Curve

TYPICAL CHARACTERISTICS  
MUN5230DW1, NSBC113EDXV6

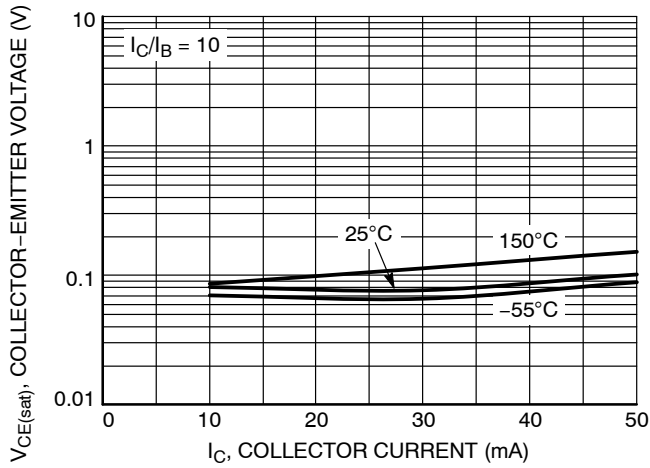


Figure 2.  $V_{CE(sat)}$  vs.  $I_C$

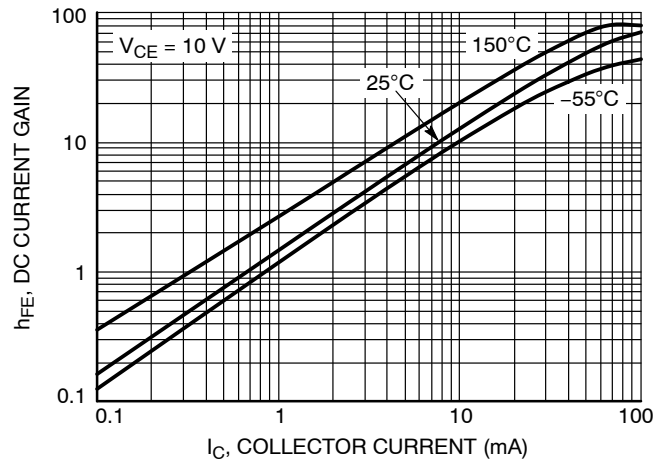


Figure 3. DC Current Gain

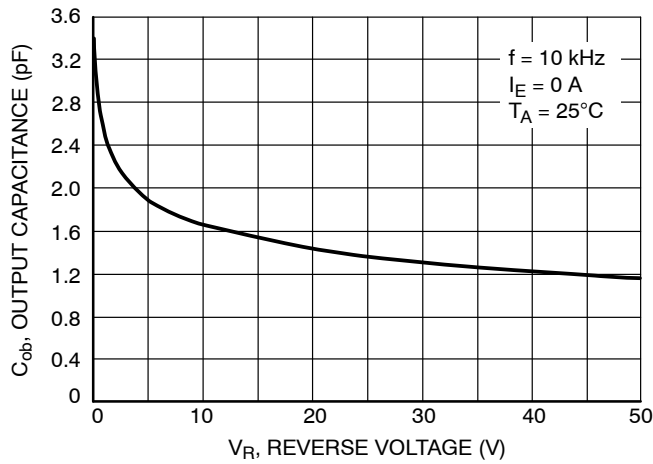


Figure 4. Output Capacitance

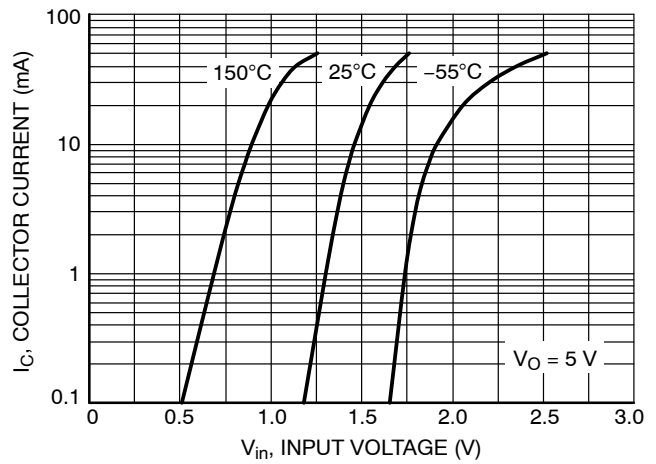


Figure 5. Output Current vs. Input Voltage

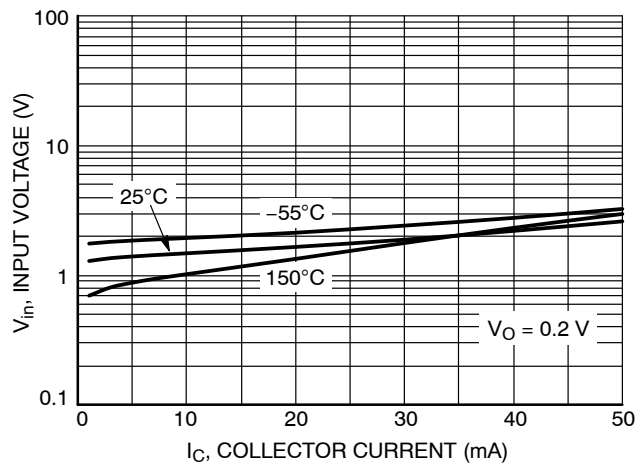


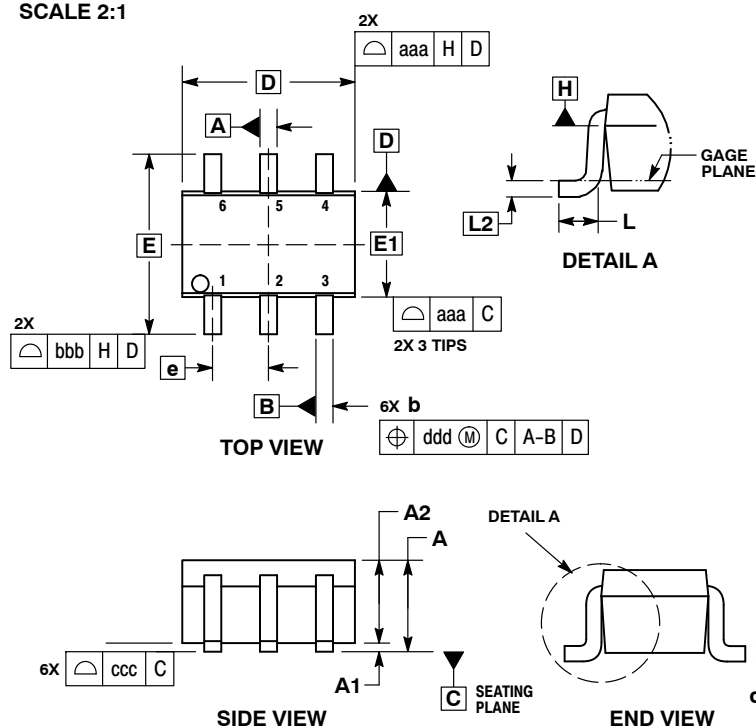
Figure 6. Input Voltage vs. Output Current

**ON**



**SC-88/SC70-6/SOT-363**  
CASE 419B-02  
ISSUE Y

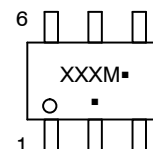
DATE 11 DEC 2012



- NOTES:**
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END.
  4. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H.
  5. DATUMS A AND B ARE DETERMINED AT DATUM H.
  6. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.
  7. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION b AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

| DIM        | MILLIMETERS |      |      | INCHES    |       |       |
|------------|-------------|------|------|-----------|-------|-------|
|            | MIN         | NOM  | MAX  | MIN       | NOM   | MAX   |
| <b>A</b>   | ---         | ---  | 1.10 | ---       | ---   | 0.043 |
| <b>A1</b>  | 0.00        | ---  | 0.10 | 0.000     | ---   | 0.004 |
| <b>A2</b>  | 0.70        | 0.90 | 1.00 | 0.027     | 0.035 | 0.039 |
| <b>b</b>   | 0.15        | 0.20 | 0.25 | 0.006     | 0.008 | 0.010 |
| <b>C</b>   | 0.08        | 0.15 | 0.22 | 0.003     | 0.006 | 0.009 |
| <b>D</b>   | 1.80        | 2.00 | 2.20 | 0.070     | 0.078 | 0.086 |
| <b>E</b>   | 2.00        | 2.10 | 2.20 | 0.078     | 0.082 | 0.086 |
| <b>E1</b>  | 1.15        | 1.25 | 1.35 | 0.045     | 0.049 | 0.053 |
| <b>e</b>   | 0.65 BSC    |      |      | 0.026 BSC |       |       |
| <b>L</b>   | 0.26        | 0.36 | 0.46 | 0.010     | 0.014 | 0.018 |
| <b>L2</b>  | 0.15 BSC    |      |      | 0.006 BSC |       |       |
| <b>aaa</b> | 0.15        |      |      | 0.006     |       |       |
| <b>bbb</b> | 0.30        |      |      | 0.012     |       |       |
| <b>ccc</b> | 0.10        |      |      | 0.004     |       |       |
| <b>ddd</b> | 0.10        |      |      | 0.004     |       |       |

### GENERIC MARKING DIAGRAM\*



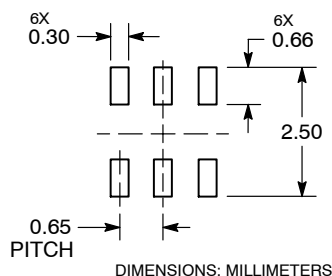
XXX = Specific Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

### RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## STYLES ON PAGE 2

|                         |                             |                                                                                                                                                                                     |
|-------------------------|-----------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
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| <b>DESCRIPTION:</b>     | <b>SC-88/SC70-6/SOT-363</b> | <b>PAGE 1 OF 2</b>                                                                                                                                                                  |

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**SC-88/SC70-6/SOT-363**  
**CASE 419B-02**  
**ISSUE Y**

DATE 11 DEC 2012

|                                                                                                                   |                                                                                                               |                                                                                                                    |                                                                                                                    |                                                                                                                    |                                                                                                              |
|-------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------|
| <b>STYLE 1:</b><br>PIN 1. EMITTER 2<br>2. BASE 2<br>3. COLLECTOR 1<br>4. EMITTER 1<br>5. BASE 1<br>6. COLLECTOR 2 | <b>STYLE 2:</b><br>CANCELLED                                                                                  | <b>STYLE 3:</b><br>CANCELLED                                                                                       | <b>STYLE 4:</b><br>PIN 1. CATHODE<br>2. CATHODE<br>3. COLLECTOR<br>4. EMITTER<br>5. BASE<br>6. ANODE               | <b>STYLE 5:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. COLLECTOR<br>4. EMITTER<br>5. BASE<br>6. CATHODE                 | <b>STYLE 6:</b><br>PIN 1. ANODE 2<br>2. N/C<br>3. CATHODE 1<br>4. ANODE 1<br>5. N/C<br>6. CATHODE 2          |
| <b>STYLE 7:</b><br>PIN 1. SOURCE 2<br>2. DRAIN 2<br>3. GATE 1<br>4. SOURCE 1<br>5. DRAIN 1<br>6. GATE 2           | <b>STYLE 8:</b><br>CANCELLED                                                                                  | <b>STYLE 9:</b><br>PIN 1. EMITTER 2<br>2. EMITTER 1<br>3. COLLECTOR 1<br>4. BASE 1<br>5. BASE 2<br>6. COLLECTOR 2  | <b>STYLE 10:</b><br>PIN 1. SOURCE 2<br>2. SOURCE 1<br>3. GATE 1<br>4. DRAIN 1<br>5. DRAIN 2<br>6. GATE 2           | <b>STYLE 11:</b><br>PIN 1. CATHODE 2<br>2. CATHODE 2<br>3. ANODE 1<br>4. CATHODE 1<br>5. CATHODE 1<br>6. ANODE 2   | <b>STYLE 12:</b><br>PIN 1. ANODE 2<br>2. ANODE 2<br>3. CATHODE 1<br>4. ANODE 1<br>5. ANODE 1<br>6. CATHODE 2 |
| <b>STYLE 13:</b><br>PIN 1. ANODE<br>2. N/C<br>3. COLLECTOR<br>4. EMITTER<br>5. BASE<br>6. CATHODE                 | <b>STYLE 14:</b><br>PIN 1. VREF<br>2. GND<br>3. GND<br>4. IOUT<br>5. VEN<br>6. VCC                            | <b>STYLE 15:</b><br>PIN 1. ANODE 1<br>2. ANODE 2<br>3. ANODE 3<br>4. CATHODE 3<br>5. CATHODE 2<br>6. CATHODE 1     | <b>STYLE 16:</b><br>PIN 1. BASE 1<br>2. EMITTER 2<br>3. COLLECTOR 2<br>4. BASE 2<br>5. EMITTER 1<br>6. COLLECTOR 1 | <b>STYLE 17:</b><br>PIN 1. BASE 1<br>2. EMITTER 1<br>3. COLLECTOR 2<br>4. BASE 2<br>5. EMITTER 2<br>6. COLLECTOR 1 | <b>STYLE 18:</b><br>PIN 1. VIN1<br>2. VCC<br>3. VOUT2<br>4. VIN2<br>5. GND<br>6. VOUT1                       |
| <b>STYLE 19:</b><br>PIN 1. IOUT<br>2. GND<br>3. GND<br>4. V CC<br>5. V EN<br>6. V REF                             | <b>STYLE 20:</b><br>PIN 1. COLLECTOR<br>2. COLLECTOR<br>3. BASE<br>4. EMITTER<br>5. COLLECTOR<br>6. COLLECTOR | <b>STYLE 21:</b><br>PIN 1. ANODE 1<br>2. N/C<br>3. ANODE 2<br>4. CATHODE 2<br>5. N/C<br>6. CATHODE 1               | <b>STYLE 22:</b><br>PIN 1. D1 (i)<br>2. GND<br>3. D2 (i)<br>4. D2 (c)<br>5. VBUS<br>6. D1 (c)                      | <b>STYLE 23:</b><br>PIN 1. Vn<br>2. CH1<br>3. Vp<br>4. N/C<br>5. CH2<br>6. N/C                                     | <b>STYLE 24:</b><br>PIN 1. CATHODE<br>2. ANODE<br>3. CATHODE<br>4. CATHODE<br>5. CATHODE<br>6. CATHODE       |
| <b>STYLE 25:</b><br>PIN 1. BASE 1<br>2. CATHODE<br>3. COLLECTOR 2<br>4. BASE 2<br>5. EMITTER<br>6. COLLECTOR 1    | <b>STYLE 26:</b><br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. DRAIN 2<br>4. SOURCE 2<br>5. GATE 2<br>6. DRAIN 1      | <b>STYLE 27:</b><br>PIN 1. BASE 2<br>2. BASE 1<br>3. COLLECTOR 1<br>4. EMITTER 1<br>5. EMITTER 2<br>6. COLLECTOR 2 | <b>STYLE 28:</b><br>PIN 1. DRAIN<br>2. DRAIN<br>3. GATE<br>4. SOURCE<br>5. DRAIN<br>6. DRAIN                       | <b>STYLE 29:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. COLLECTOR<br>4. EMITTER<br>5. BASE/ANODE<br>6. CATHODE          | <b>STYLE 30:</b><br>PIN 1. SOURCE 1<br>2. DRAIN 2<br>3. DRAIN 2<br>4. SOURCE 2<br>5. GATE 1<br>6. DRAIN 1    |

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

|                         |                             |                                                                                                                                                                                     |
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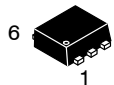
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# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

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ON



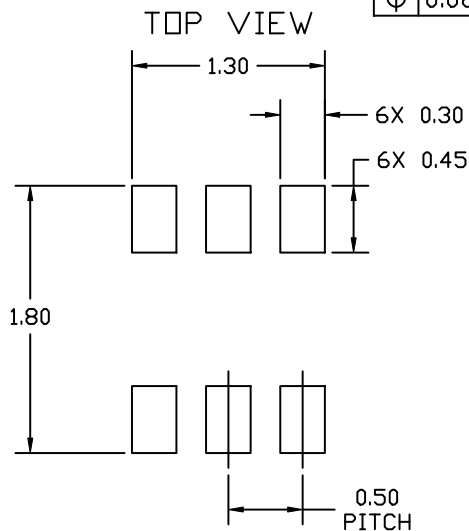
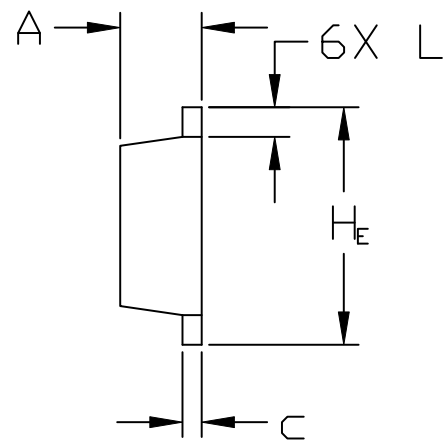
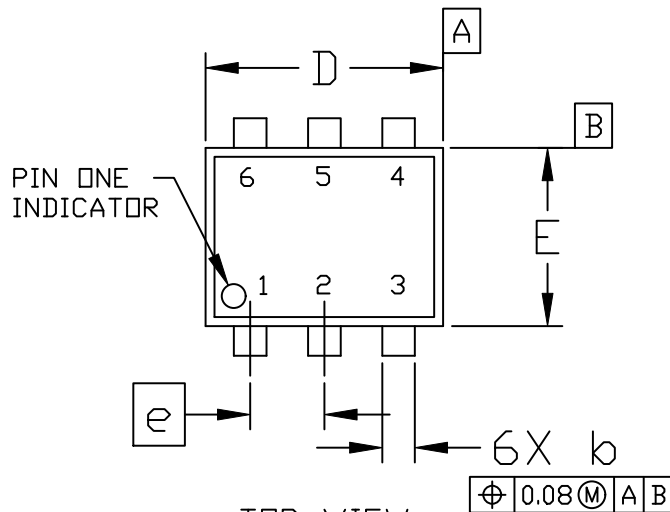
SCALE 4:1

**SOT-563, 6 LEAD**  
CASE 463A  
ISSUE H

DATE 26 JAN 2021

### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.



SIDE VIEW

| DIM            | MILLIMETERS |      |      |
|----------------|-------------|------|------|
|                | MIN.        | NOM. | MAX. |
| A              | 0.50        | 0.55 | 0.60 |
| b              | 0.17        | 0.22 | 0.27 |
| c              | 0.08        | 0.13 | 0.18 |
| D              | 1.50        | 1.60 | 1.70 |
| E              | 1.10        | 1.20 | 1.30 |
| e              | 0.50 BSC    |      |      |
| L              | 0.10        | 0.20 | 0.30 |
| H <sub>E</sub> | 1.50        | 1.60 | 1.70 |

### RECOMMENDED MOUNTING FOOTPRINT\*

- \* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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| <b>DESCRIPTION:</b>     | <b>SOT-563, 6 LEAD</b> | <b>PAGE 1 OF 2</b>                                                                                                                                                               |

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**SOT-563, 6 LEAD**  
CASE 463A  
ISSUE H

DATE 26 JAN 2021

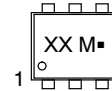
|                                                                                                            |                                                                                                            |                                                                                                                      |
|------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------|
| STYLE 1:<br>PIN 1. EMITTER 1<br>2. BASE 1<br>3. COLLECTOR 2<br>4. EMITTER 2<br>5. BASE 2<br>6. COLLECTOR 1 | STYLE 2:<br>PIN 1. EMITTER 1<br>2. EMITTER 2<br>3. BASE 2<br>4. COLLECTOR 2<br>5. BASE 1<br>6. COLLECTOR 1 | STYLE 3:<br>PIN 1. CATHODE 1<br>2. CATHODE 1<br>3. ANODE/ANODE 2<br>4. CATHODE 2<br>5. CATHODE 2<br>6. ANODE/ANODE 1 |
|------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------|

|                                                                                                       |                                                                                              |                                                                                                |
|-------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------|
| STYLE 4:<br>PIN 1. COLLECTOR<br>2. COLLECTOR<br>3. BASE<br>4. EMITTER<br>5. COLLECTOR<br>6. COLLECTOR | STYLE 5:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. ANODE<br>4. ANODE<br>5. CATHODE<br>6. CATHODE | STYLE 6:<br>PIN 1. CATHODE<br>2. ANODE<br>3. CATHODE<br>4. CATHODE<br>5. CATHODE<br>6. CATHODE |
|-------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------|

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|----------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------|
| STYLE 7:<br>PIN 1. CATHODE<br>2. ANODE<br>3. CATHODE<br>4. CATHODE<br>5. ANODE<br>6. CATHODE | STYLE 8:<br>PIN 1. DRAIN<br>2. DRAIN<br>3. GATE<br>4. SOURCE<br>5. DRAIN<br>6. DRAIN | STYLE 9:<br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. DRAIN 2<br>4. SOURCE 2<br>5. GATE 2<br>6. DRAIN 1 |
|----------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------|

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|-----------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------|
| STYLE 10:<br>PIN 1. CATHODE 1<br>2. N/C<br>3. CATHODE 2<br>4. ANODE 2<br>5. N/C<br>6. ANODE 1 | STYLE 11:<br>PIN 1. EMITTER 2<br>2. BASE 2<br>3. COLLECTOR 1<br>4. EMITTER 1<br>5. BASE 1<br>6. COLLECTOR 2 |
|-----------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------|

**GENERIC  
MARKING DIAGRAM\***



XX = Specific Device Code  
M = Month Code  
■ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

|                         |                        |                                                                                                                                                                                     |
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